

XN04401 (XN4401)

Silicon PNP epitaxial planar type

For general amplification

■ Features

- Two elements incorporated into one package
- Reduction of the mounting area and assembly cost by one half

■ Basic Part Number

- 2SB0709A (2SB709A) × 2

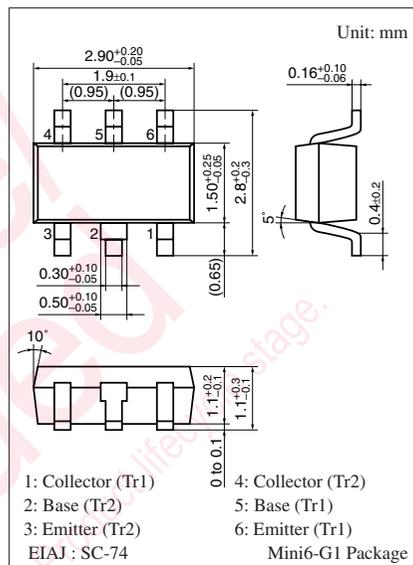
■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

| Parameter | Symbol | Rating | Unit |
|---------------------------------------|------------------|-------------|------------------|
| Collector-base voltage (Emitter open) | V_{CBO} | -60 | V |
| Collector-emitter voltage (Base open) | V_{CEO} | -50 | V |
| Emitter-base voltage (Collector open) | V_{EBO} | -7 | V |
| Collector current | I_{C} | -100 | mA |
| Peak collector current | I_{CP} | -200 | mA |
| Total power dissipation | P_{T} | 300 | mW |
| Junction temperature | T_{j} | 150 | $^\circ\text{C}$ |
| Storage temperature | T_{stg} | -55 to +150 | $^\circ\text{C}$ |

■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

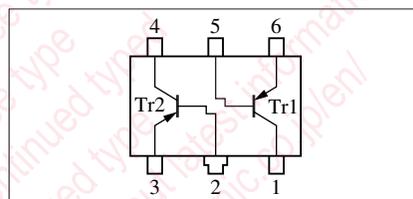
| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|---|----------------------|---|-----|------|------|---------------|
| Collector-base voltage (Emitter open) | V_{CBO} | $I_{\text{C}} = -10 \mu\text{A}, I_{\text{E}} = 0$ | -60 | | | V |
| Collector-emitter voltage (Base open) | V_{CEO} | $I_{\text{C}} = -2 \text{ mA}, I_{\text{B}} = 0$ | -50 | | | V |
| Emitter-base voltage (Collector open) | V_{EBO} | $I_{\text{E}} = -10 \mu\text{A}, I_{\text{C}} = 0$ | -7 | | | V |
| Collector-base cutoff current (Emitter open) | I_{CBO} | $V_{\text{CB}} = -20 \text{ V}, I_{\text{E}} = 0$ | | | -0.1 | μA |
| Collector-emitter cutoff current (Base open) | I_{CEO} | $V_{\text{CE}} = -10 \text{ V}, I_{\text{B}} = 0$ | | | -100 | μA |
| Forward current transfer ratio | h_{FE} | $V_{\text{CE}} = -10 \text{ V}, I_{\text{C}} = -2 \text{ mA}$ | 160 | | 460 | — |
| Collector-emitter saturation voltage | $V_{\text{CE(sat)}}$ | $I_{\text{C}} = -100 \text{ mA}, I_{\text{B}} = -10 \text{ mA}$ | | -0.3 | -0.5 | V |
| Transition frequency | f_{T} | $V_{\text{CB}} = -10 \text{ V}, I_{\text{E}} = 1 \text{ mA}, f = 200 \text{ MHz}$ | | 80 | | MHz |
| Collector output capacitance (Common base, input open circuited) | C_{ob} | $V_{\text{CB}} = -10 \text{ V}, I_{\text{E}} = 0, f = 1 \text{ MHz}$ | | 2.7 | | pF |

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

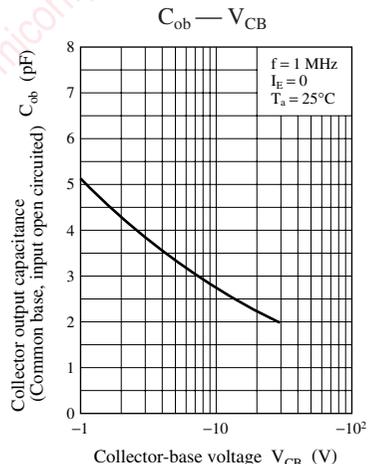
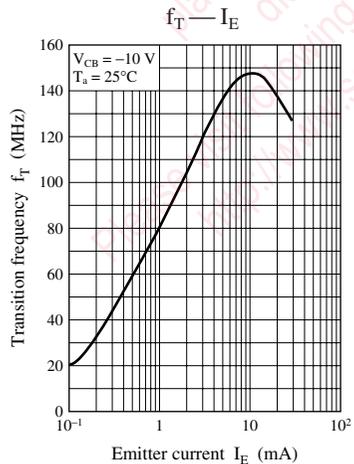
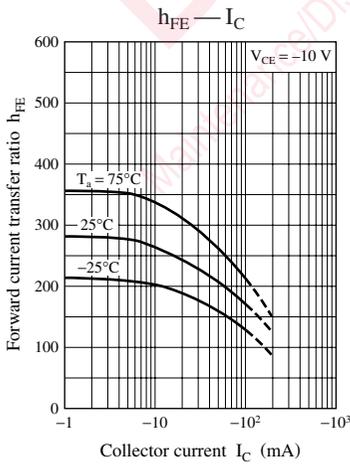
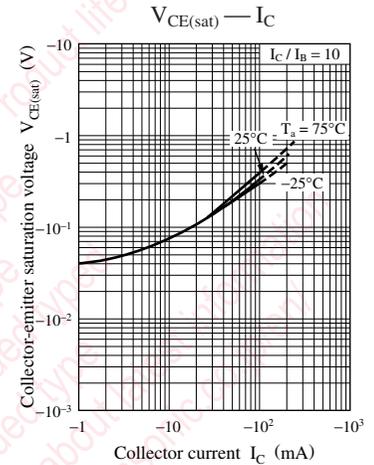
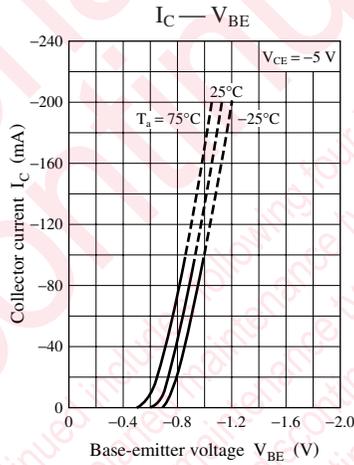
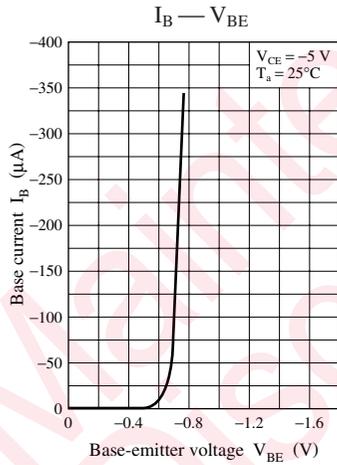
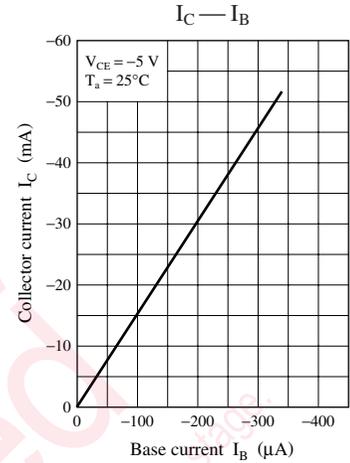
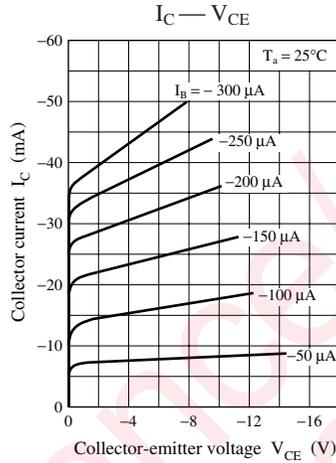
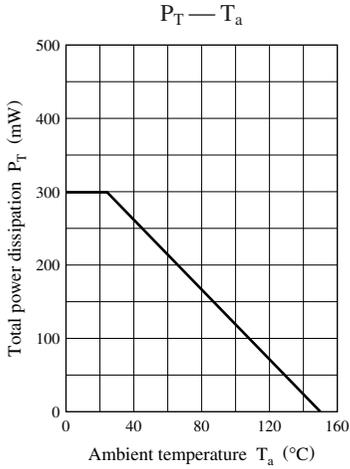


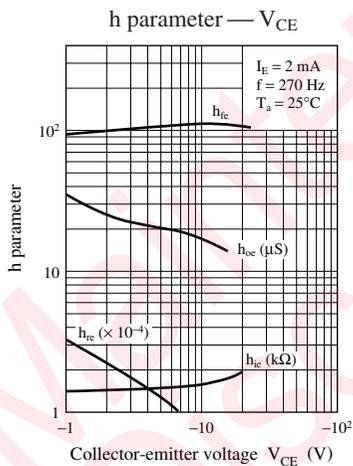
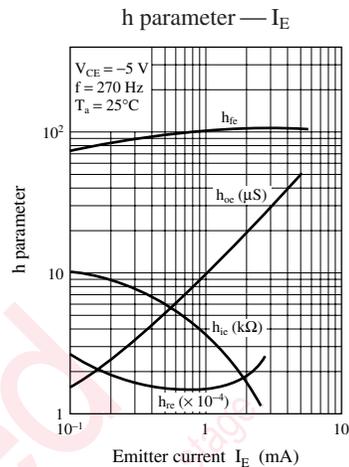
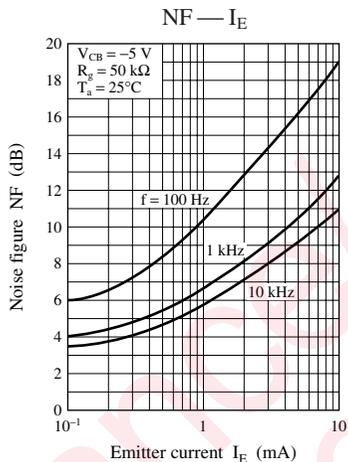
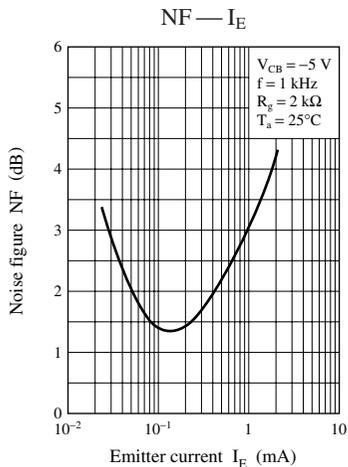
Marking Symbol: 5K

Internal Connection



Note) The part number in the parenthesis shows conventional part number.





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